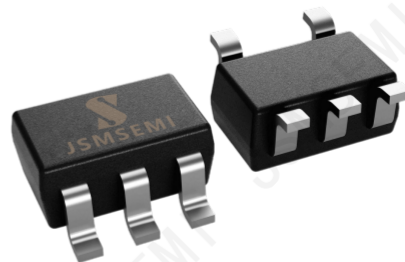


Description

This single buffer/driver is designed for 1.65V to 5.5V VCC operation. The output of the SN74LVC1G07 device is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32mA. The SN74LVC1G07 is available in Green SOT23-5 and SOT-353 packages. It operates over an ambient temperature range of -40°C to +125°C.



Applications

- AV receiver
- Blu-ray player and home theater
- DVD recorder and player
- Desktop or notebook PC
- Digital radio or internet radio player
- Digital Video Camera (DVC)
- Embedded PC
- GPS: personal navigation device
- Mobile internet device
- Network projector front end
- Portable media player
- Pro audio mixer
- Smoke detector
- Solid State Drive (SSD): enterprise
- High-definition (HDTV)
- Tablet: enterprise
- Audio dock: portable
- DLP front projection system
- DVR and DVS
- Digital Picture Frame (DPF)
- Digital still camera

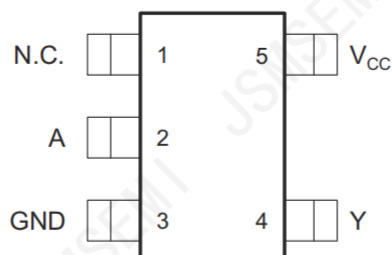
Features

- Packages: SOT23-5, SOT-353(SC70-5)
- Supports 5V V_{CC} operation
- Input and open-drain output accept voltages up to 5.5V
- Can translate up or down
- Typ t_{pd} of 4.2ns at 3.3V
- Low power consumption, 1μA maximum I_{CC}
- ±24mA output drive at 3V
- I_{off} supports live insertion, partial-power-down mode, and back-drive protection
- Latch-up performance exceeds 100mA
- ESD protection exceeds JESD 22
 - 2000V Human-body model
 - 200V Machine model
 - 1000V Charged-device model
- Operating Temperature Range: -40°C to +125°C
- RoSH compatible

Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SN74LVC1G07DBVR-JSM	SOT-23-5L	C075	-40 to 125°C	3	TR&3000	Rohs
SN74LVC1G07DCKR-JSM	SOT-353	CV5	-40 to 125°C	3	TR&3000	Rohs

Pin Configuration and Functions



TOP VIEW

Pin Functions

PIN		DESCRIPTION
DBV, DCK, DRL	NAME	
1	NC	Not connected
2	A	Input
3	GND	Ground
4	Y	Output
5	V _{CC}	Power pin

Specifications

Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range	-0.5	6.5	V
V _I	Input voltage range ⁽²⁾	-0.5	6.5	V
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
V _O	Voltage range applied to any output in the high or low state ^{(2) (3)}	-0.5	6.5	V
I _{IK}	Input clamp current		-50	mA
I _{OK}	Output clamp current		-50	mA
I _O	Continuous output current		±50	mA
	Continuous current through V _{CC} or GND		±100	mA
T _{stg}	Storage temperature range	-65	150	°C
T _j	Junction temperature range		150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the Recommended Operating Conditions table.

ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM)	2000
		Charged device model (CDM)	1000

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage	Operating	1.65	5.5	V
		Data retention only		1.5	
V _{IH}	High-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}		V
		V _{CC} = 2.3 V to 2.7 V		1.7	
		V _{CC} = 3 V to 3.6 V		2	
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}		
V _{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V		0.15 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		0.7	
		V _{CC} = 3 V to 3.6 V		0.8	
		V _{CC} = 4.5 V to 5.5 V		0.15 × V _{CC}	
V _I	Input voltage		0	5.5	V
V _O	Output voltage		0	5.5	V
I _{OL}	Low-level output current	V _{CC} = 1.65 V		4	mA
		V _{CC} = 2.3 V		8	
		V _{CC} = 3 V		16	
				24	
		V _{CC} = 4.5 V		32	
Δt/Δv	Input transition rise or fall rate	V _{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	ns/V
		V _{CC} = 3.3 V ± 0.3 V		10	
		V _{CC} = 5 V ± 0.5 V		5	
T _A	Operating free-air temperature	DSBGA package	−40	85	°C
		All other packages	−40	125	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Thermal Information

THERMAL METRIC		SN74LVC1G07		UNIT
		DBV	DCK	
		5 PINS	5 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	257.1	271.0	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	163.7	197.5	
R _{θJB}	Junction-to-board thermal resistance	64.4	58.6	
Ψ _{JT}	Junction-to-top characterization parameter	15.6	15.6	
Ψ _{JB}	Junction-to-board characterization parameter	62.2	56.2	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	—	—	

Electrical Characteristics—DC Limit Changes

over recommended operating free-air temperature range (Full=-40°C to +125°C, typical values are at T_A = +25°C, unless otherwise noted.)⁽¹⁾

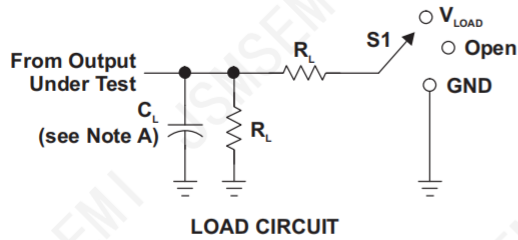
PARAMETER		TEST CONDITIONS	V _{CC}	TEMP	MIN	TYP	MAX	UNIT
V _{OL}		I _{OL} = 100μA	1.65V to 5.5V	Full			0.1	V
		I _{OL} = 4mA	1.65V				0.45	
		I _{OL} = 8mA	2.3V				0.3	
		I _{OL} = 16mA	3V				0.4	
		I _{OL} = 24mA					0.55	
		I _{OL} = 32mA	4.5V				0.55	
I _I	A input	V _I =5.5V or GND	0V to 5.5V	+25°C		±0.1	±1	μA
				Full			±5	
I _{off}		V _I or V _O =5.5V	0	+25°C		±0.1	±1	μA
				Full			±10	
I _{CC}		V _I =5.5V or GND, I _O =0	1.65V to 5.5V	+25°C		0.1	1	μA
				Full			10	
ΔI _{CC}		One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND	3V to 5.5V	Full			500	μA

Electrical Characteristics—AC Limit Changes

PARAMETER	SYMBOL	TEST CONDITIONS		TEMP	MIN	TYP	MAX	UNIT
Propagation Delay	t _{pd}	V _{CC} =1.8V±0.15V	C _L =30pF, R _L =1kΩ	Full		6.4		ns
		V _{CC} =2.5V±0.2V	C _L =30pF, R _L =500Ω	Full		4.5		
		V _{CC} =3.3V±0.3V	C _L =50pF, R _L =500Ω	Full		4.2		
		V _{CC} =5V±0.5V	C _L =50pF, R _L =500Ω	Full		3.7		
Input Capacitance	C _i	V _{CC} =3.3V	V _I =V _{CC} or GND	+25°C		4		pF
Power dissipation capacitance	C _{pd}	V _{CC} =1.8V	f=10MHz	+25°C		3		pF
		V _{CC} =2.5V				3		
		V _{CC} =3.3V				4		
		V _{CC} =5V				6		

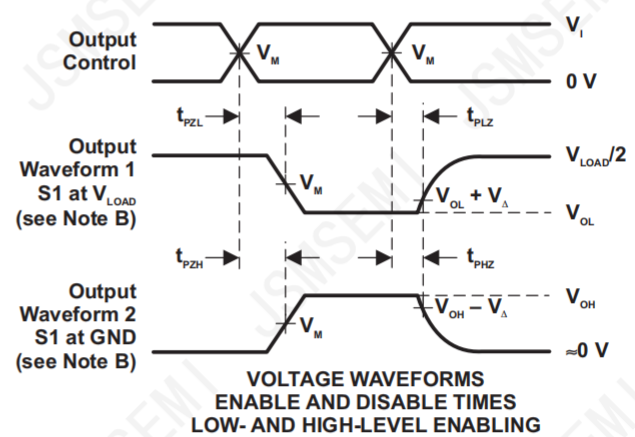
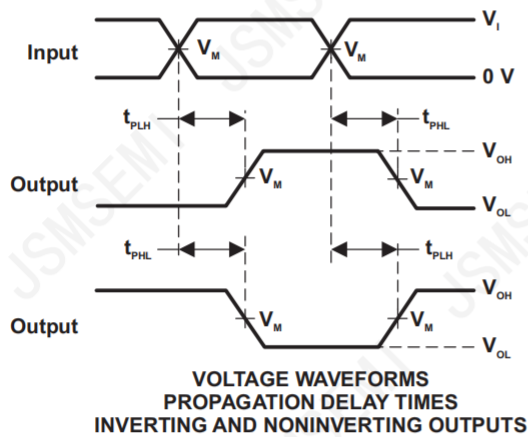
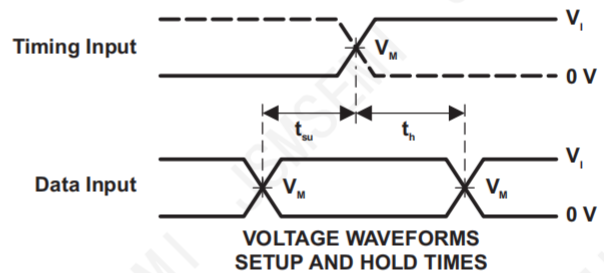
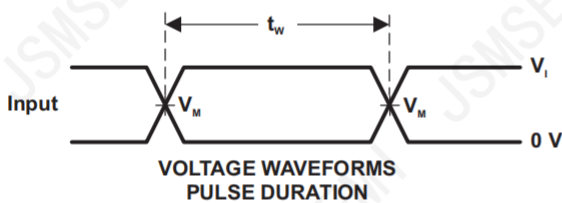
(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Parameter Measurement Information



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L		R_L		V_{Δ}
	V_I	t_r/t_f							
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M Ω	1k Ω	0.15V
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	30pF	1M Ω	500 Ω	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	50pF	1M Ω	500 Ω	0.3V
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	50pF	1M Ω	500 Ω	0.3V



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_o = 50 \Omega$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{SU} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

Detailed Description

Overview

The SN74LVC1G07 device contains one open-drain buffer with a maximum sink current of 32 mA. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Functional Block Diagram



Feature Description

- Wide operating voltage range.
 - Operates from 1.65 V to 5.5 V.
- Allows down voltage translation.
- Inputs and outputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

Device Functional Modes

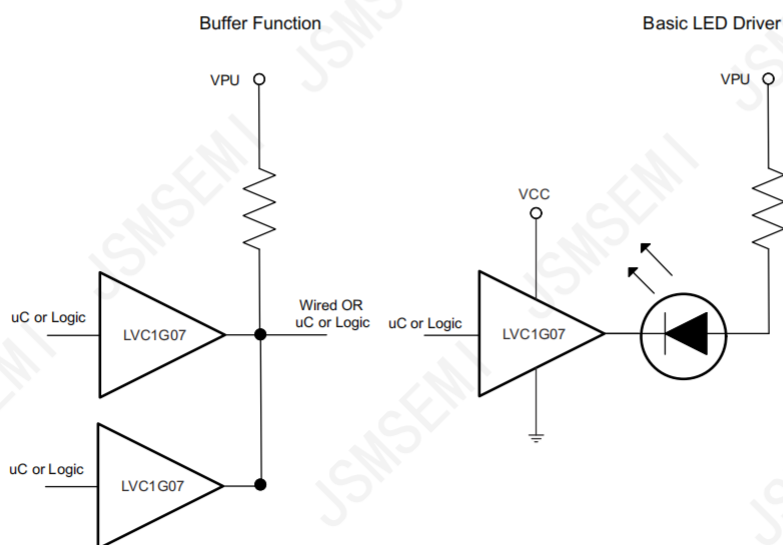
Function Table

INPUT	OUTPUT
A	Y
L	L
H	Z

Application Information

The SN74LVC1G07 is a high drive CMOS device that can be used to implement a high output drive buffer, such as an LED application. It can sink 32 mA of current at 4.5 V making it ideal for high drive and wired-OR/AND functions. It is good for high speed applications up to 100 MHz. The inputs are 5.5 V tolerant allowing it to translate up/down to V_{CC} .

Typical Application



Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each Vcc pin should have a good bypass capacitor to prevent power disturbance. A 0.1 μ F capacitor is recommended for devices with a single supply. If there are multiple Vcc pins then a 0.01 μ F or 0.022 μ F capacitor is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. 0.1 μ F and 1 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

Layout

Layout Guidelines

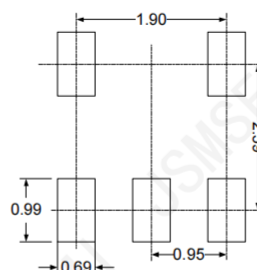
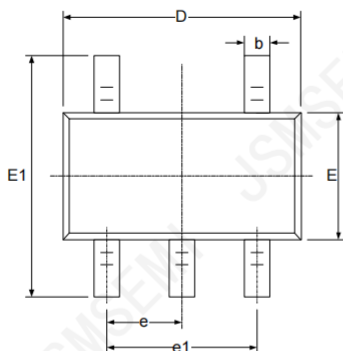
When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally, they will be tied to Gnd or Vcc, whichever is more convenient.

Layout Example

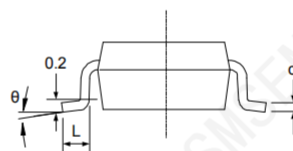
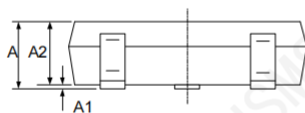


Package Information

SOT-23-5L



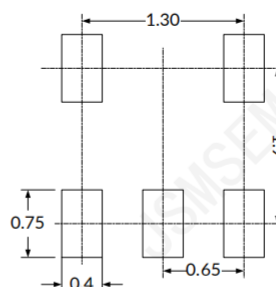
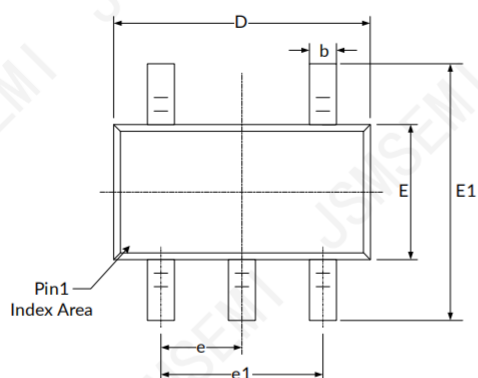
RECOMMENDED LAND PATTERN (Unit: mm)



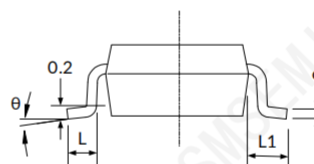
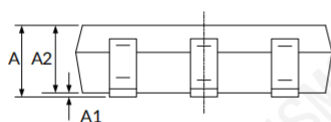
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Package Information

SOT-353(SC70-5)



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D ⁽¹⁾	2.000	2.200	0.079	0.087
E ⁽¹⁾	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650(BSC)		0.026(BSC)	
e1	1.300(BSC)		0.051(BSC)	
L	0.260	0.460	0.010	0.018
L1	0.525		0.021	
θ	0°	8°	0°	8°

Revision History

Rev.	Change	Date
V1.0	Initial version	6/27/2021

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